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# HMC648ALP6E

v00.0915

## GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 2.9 - 3.9 GHz

### Typical Applications

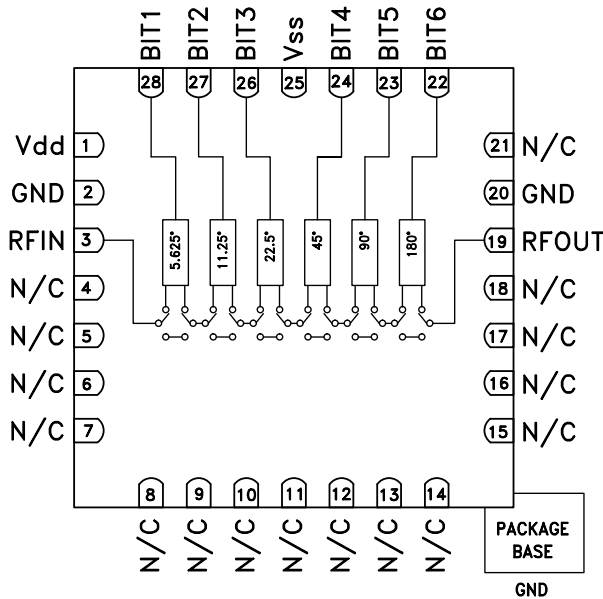
The HMC648ALP6E is ideal for:

- EW Receivers
- Weather & Military Radar
- Satellite Communications
- Beamforming Modules
- Phase Cancellation

### Features

- Low RMS Phase Error: 1.2°
- Low Insertion Loss: 5 dB
- High Linearity: +45 dBm
- Positive Control Logic
- 360° Coverage, LSB = 5.625°
- 28 Lead 6x6mm SMT Package: 36mm<sup>2</sup>

### Functional Diagram



### General Description

The HMC648ALP6E is a 6-bit digital phase shifter which is rated from 2.9 - 3.9 GHz, providing 360 degrees of phase coverage, with a LSB of 5.625 degrees. The HMC648ALP6E features very low RMS phase error of 1.2 degrees and extremely low insertion loss variation of ±0.5 dB across all phase states. This high accuracy phase shifter is controlled with positive control logic of 0/+5V. The HMC648ALP6E is housed in a compact 6x6 mm plastic leadless SMT package and is internally matched to 50 Ohms with no external components.

### Electrical Specifications

$T_A = +25^\circ\text{C}$ ,  $V_{SS} = -5\text{V}$ ,  $V_{DD} = +5\text{V}$ , Control Voltage = 0/ +5V, 50 Ohm System

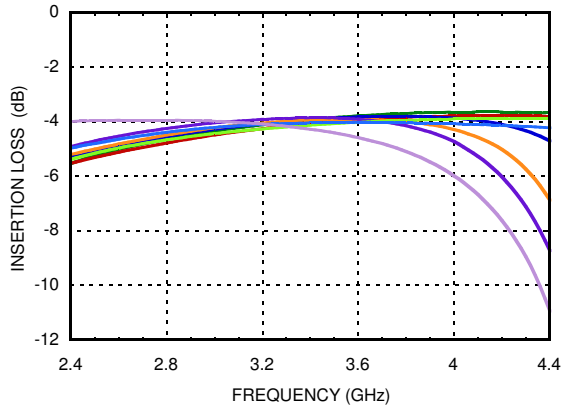
Parameter	Min.	Typ.	Max.	Units
Frequency Range	2.9		3.9	GHz
Insertion Loss*		5	8	dB
Input Return Loss*		16		dB
Output Return Loss*		17		dB
Phase Error*		±5	+10 / -15	deg
RMS Phase Error		1.2		deg
Insertion Loss Variation*		±0.5		dB
Input Power for 1 dB Compression		31		dBm
Input Third Order Intercept		45		dBm
Control Voltage Current		35	250	µA
Bias Control Current		5	15	mA

\*Note: Major States Shown

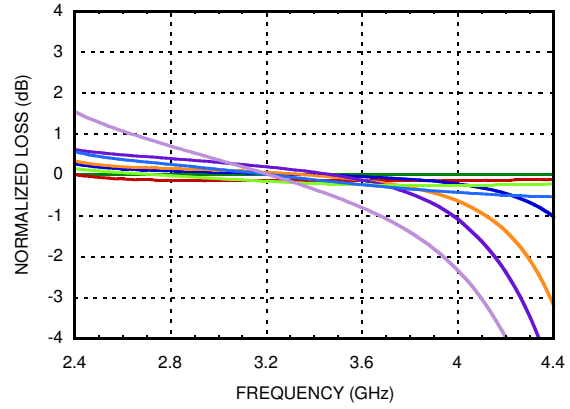


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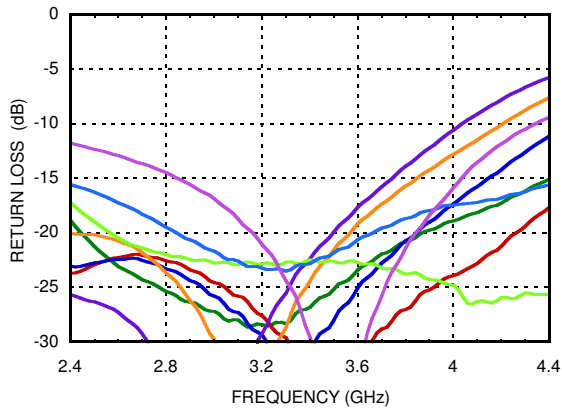
**Insertion Loss, Major States Only**



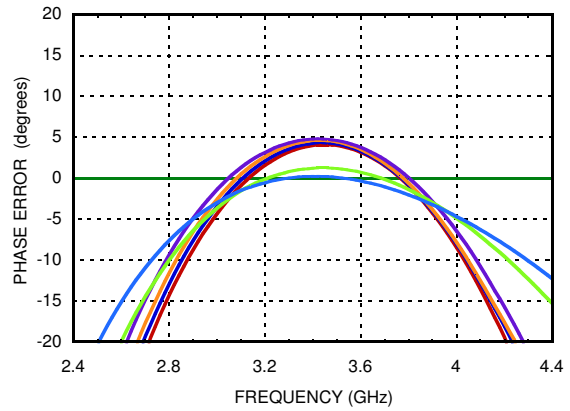
**Normalized Loss, Major States Only**



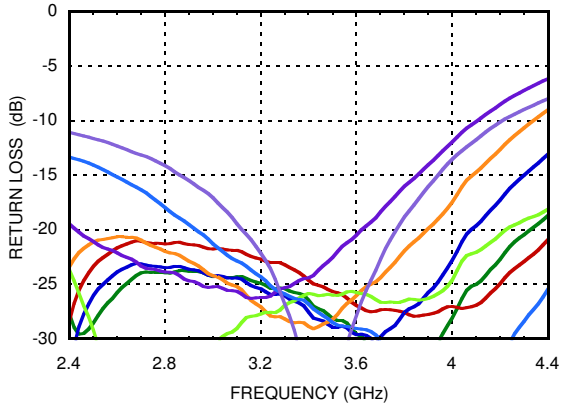
**Input Return Loss, Major States Only**



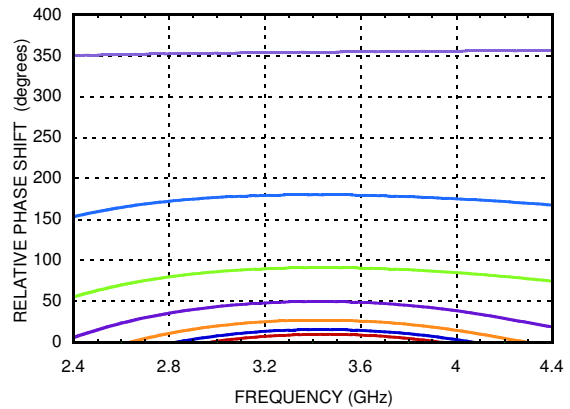
**Phase Error, Major States Only**



**Output Return Loss, Major States Only**



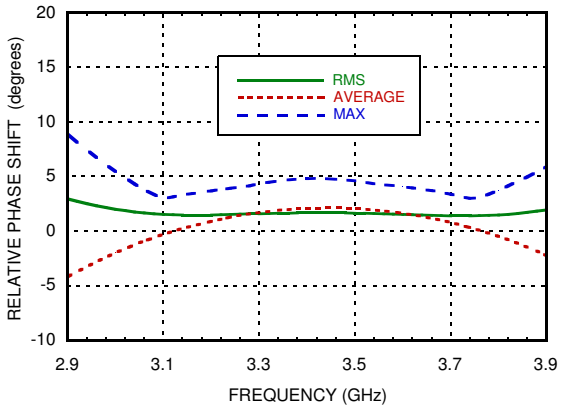
**Relative Phase Shift  
 Major States Including All Bits**



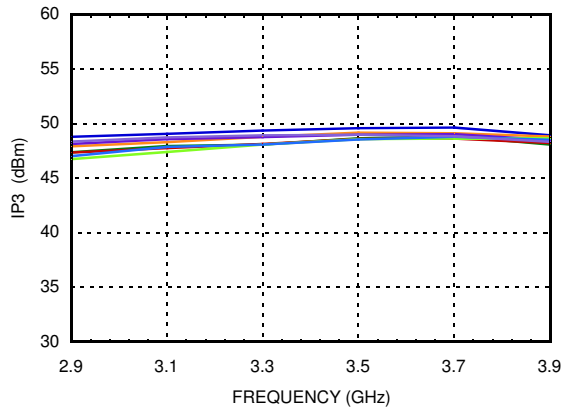


**GaAs MMIC 6-BIT DIGITAL  
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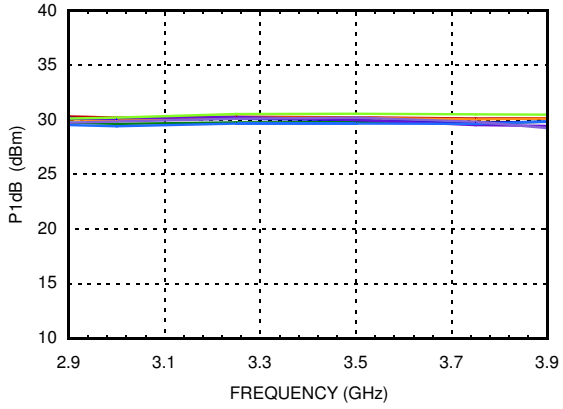
**Relative Phase Shift,  
RMS, Average, Max, All States**



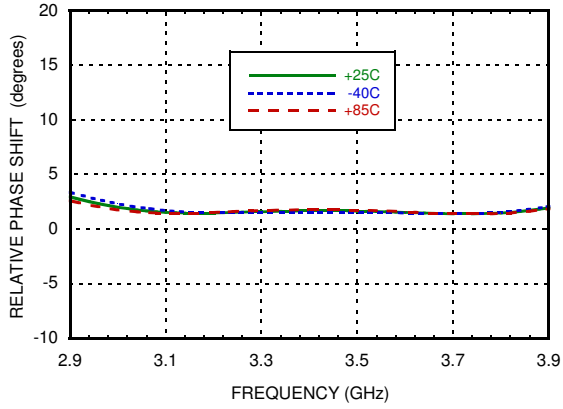
**Input IP3, Major States Only**



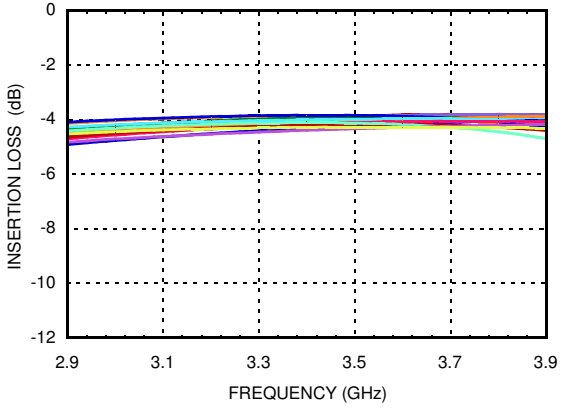
**Input P1dB, Major States Only**



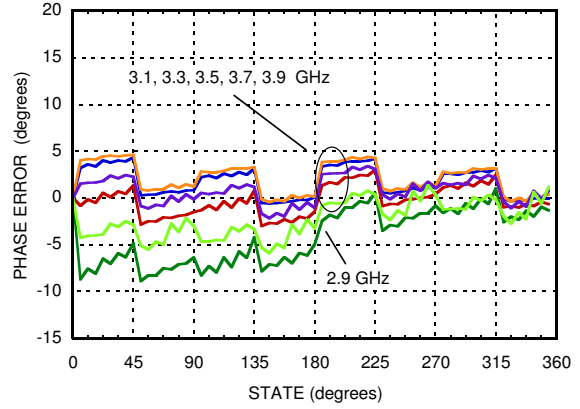
**RMS Phase Error vs. Temperature**



**Insertion Loss vs. Temperature,  
Major States Only**



**Phase Error vs. State**





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**Absolute Maximum Ratings**

Input Power (RFIN)	33 dBm (T= +85 °C)
Bias Voltage Range (Vdd)	-0.2 to +12V
Bias Voltage Range (Vss)	+0.2 to -12V
Channel Temperature (Tc)	150 °C
Thermal Resistance (channel to ground paddle)	120 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity	Class1A Passed 250V



**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**

**Bias Voltage & Current**

Vdd	Idd
5.0	5.2mA
Vss	Iss
-5.0	5.2mA

**Control Voltage**

State	Bias Condition
Low (0)	0 to 0.2 Vdc
High (1)	Vdd ±0.2 Vdc @ 35 µA Typ.

**Truth Table**

Control Voltage Input						Phase Shift (Degrees) RFIN - RFOUT
Bit 1	Bit 2	Bit 3	Bit 4	Bit 5	Bit 6	
0	0	0	0	0	0	Reference*
1	0	0	0	0	0	5.625
0	1	0	0	0	0	11.25
0	0	1	0	0	0	22.5
0	0	0	1	0	0	45.0
0	0	0	0	1	0	90.0
0	0	0	0	0	1	180.0
1	1	1	1	1	1	354.375

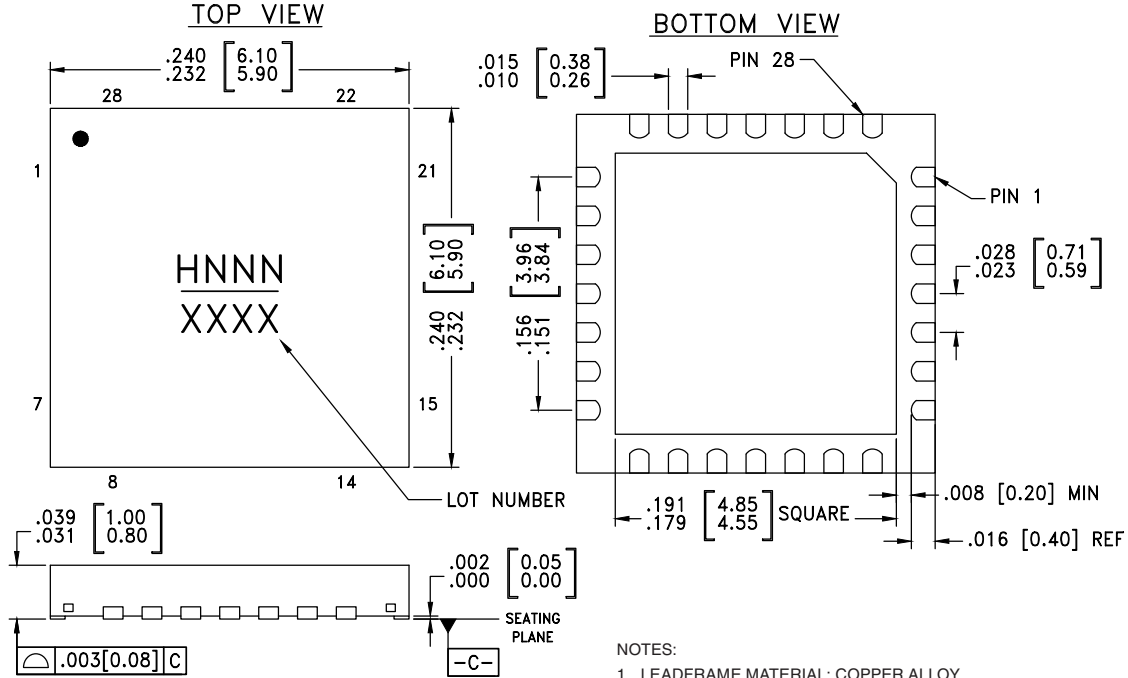
Any combination of the above states will provide a phase shift approximately equal to the sum of the bits selected.

\*Reference corresponds to monotonic setting



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**Outline Drawing**



- NOTES:
1. LEADFRAME MATERIAL: COPPER ALLOY
  2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
  3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
  4. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
  5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
  6. CLASSIFIED AS MOISTURE SENSITIVITY LEVEL (MSL) 3.

**Package Information**

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC648ALP6E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 <sup>[1]</sup>	H648A XXXX

[1] Max peak reflow temperature of 260 °C  
[2] 4-Digit lot number XXXX



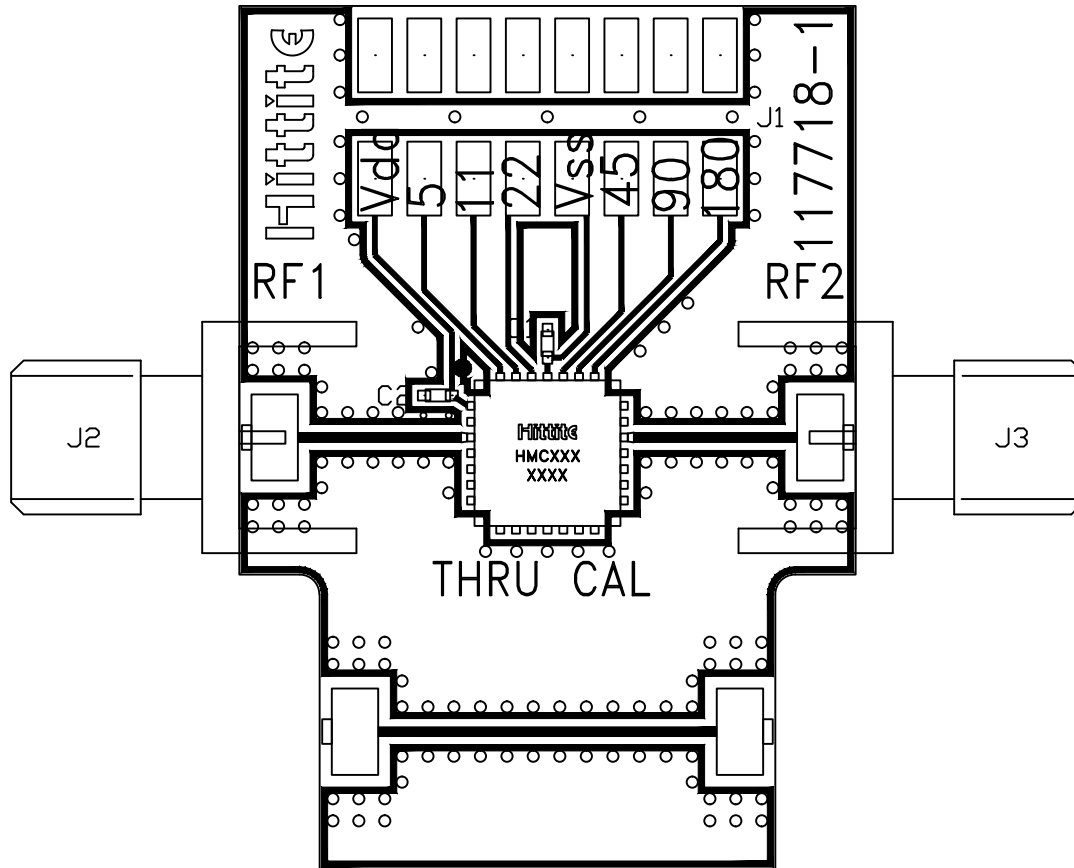
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**Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	Vdd	Voltage supply.	
2, 20	GND	These pins and exposed ground paddle must be connected to RF/DC ground.	
3	RFIN	This port is DC coupled and matched to 50 Ohms.	
4 - 18	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
19	RFOUT	This port is DC coupled and matched to 50 Ohms.	
22 - 24, 26 - 28	BIT6, BIT5, BIT4, BIT3, BIT2, BIT1	Control Input. See truth table and control voltage tables.	
25	Vss	Voltage supply.	



**Evaluation PCB**



**List of Materials for Evaluation PCB 117720 [1][3]**

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3	Header 2mm, 16 Pin
C1, C2	1000pF Capacitor, 0402 Pkg.
U1	HMC648ALP6E 6-Bit Digital Phase Shifter
PCB [2]	117718 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

[3] Please refer to part's pin description and functional diagram for pin out assignments on evaluation board.

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.



**Notes:**

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### Офис по работе с юридическими лицами:

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